

Weiqin Ao

List of Publications by Year in descending order

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#	ARTICLE	IF	CITATIONS
1	Synergistic Compositionalâ€œMechanicalâ€œThermal Effects Leading to a Record High $\langle i \rangle zT \langle /i \rangle$ in n-Type $V_{2/3}VI_{3/3}$ Alloys Through Progressive Hot Deformation. <i>Advanced Functional Materials</i> , 2018, 28, 1803617.	14.9	73
2	Suppression of the lattice thermal conductivity in NbFeSb-based half-Heusler thermoelectric materials through high entropy effects. <i>Scripta Materialia</i> , 2018, 157, 129-134.	5.2	62
3	Simultaneous Enhancement of the Thermoelectric and Mechanical Performance in One-Step Sintered n-Type $Bi_{2/2}Te_{3/3}$ -Based Alloys via a Facile $MgB_{2/2}$ Doping Strategy. <i>ACS Applied Materials & Interfaces</i> , 2019, 11, 45746-45754.	8.0	58
4	Stacking Fault-Induced Minimized Lattice Thermal Conductivity in the High-Performance GeTe-Based Thermoelectric Materials upon $Bi_{2/2}Te_{3/3}$ Alloying. <i>ACS Applied Materials & Interfaces</i> , 2019, 11, 20064-20072.	8.0	57
5	Discovery of low-temperature GeTe-based thermoelectric alloys with high performance competing with $Bi_{2/2}Te_{3/3}$. <i>Journal of Materials Chemistry A</i> , 2020, 8, 1660-1667.	10.3	43
6	Band convergence and carrier-density fine-tuning as the electronic origin of high-average thermoelectric performance in Pb-doped GeTe-based alloys. <i>Journal of Materials Chemistry A</i> , 2020, 8, 11370-11380.	10.3	41
7	Continuously Enhanced Structural Disorder To Suppress the Lattice Thermal Conductivity of ZrNiSn-Based Half-Heusler Alloys by Multielement and Multisite Alloying with Very Low Hf Content. <i>ACS Applied Materials & Interfaces</i> , 2019, 11, 13397-13404.	8.0	38
8	n- $Bi_{2/2}Sb_{x/3}Te_{3/3}$: A Promising Alternative to Mainstream Thermoelectric Material n- $Bi_{2/2}Te_{3/3}$ near Room Temperature. <i>ACS Applied Materials & Interfaces</i> , 2020, 12, 31619-31627.	8.0	33
9	Near-room-temperature thermoelectric materials and their application prospects in geothermal power generation. <i>Geomechanics and Geophysics for Geo-Energy and Geo-Resources</i> , 2020, 6, 1.	2.9	24
10	(GeTe) $_{1-x}$ (AgSnSe $_{2/2}$) $_x$: Strong Atomic Disorder-Induced High Thermoelectric Performance near the Ioffeâ€œRegel Limit. <i>ACS Applied Materials & Interfaces</i> , 2021, 13, 47081-47089.	8.0	22
11	Zr vacancy interfaces: an effective strategy for collaborative optimization of ZrNiSn-based thermoelectric performance. <i>Journal of Materials Chemistry A</i> , 2019, 7, 26053-26061.	10.3	16
12	Effects on phase transition and thermoelectric properties in the Pb-doped GeTe-Bi $_2$ Te $_3$ alloys with thermal annealing. <i>Journal of Alloys and Compounds</i> , 2019, 808, 151747.	5.5	10
13	AgNi Alloy As a Suitable Barrier Layer Material for NbFeSb-Based Half-Heusler Thermoelectric Modules. <i>Journal of Electronic Materials</i> , 2019, 48, 6815-6822.	2.2	9
14	Effects of Sc, Ti, Hf, V, Nb and Ta doping on the properties of ZrNiSn alloys. <i>Journal of Materials Science</i> , 2019, 54, 10325-10334.	3.7	9
15	Impact of Sm alloying and thermal annealing on the structural and thermoelectric properties of (GeTe) $_{0.85}$ (Pb $_{1-x}$ Sm $_x$ Te) $_{0.15}$ alloys. <i>Journal of Alloys and Compounds</i> , 2018, 755, 184-191.	5.5	7
16	Improvement of the thermoelectric properties of GeTe- and SnTe-based semiconductors aided by the engineering based on phase diagram. <i>International Journal of Materials Research</i> , 2022, 113, 340-350.	0.3	1
17	Ternary compounds and isothermal section in Luâ€œFeâ€œGa ternary system at 773 K. <i>Phase Transitions</i> , 2013, 86, 585-597.	1.3	0